

November 2011

MPSA64 / MMBTA64 / PZTA64 PNP Darlington Transistor

Features

- This device is designed for applications requiring extremely high current gain at currents to 800 mA.
- Sourced from Process 61.



Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	-30	V
V _{CBO}	Collector-Base Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-10	V
I _C	Collector Current - Continuous	-1.2	Α
T _{J,} T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle

Thermal Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Max.			Units
		MPSA64	*MMBTA64	**PZTA64	Office
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

^{*} Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

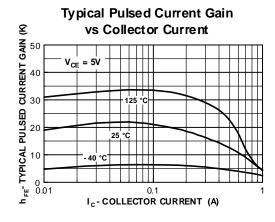
^{**} Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

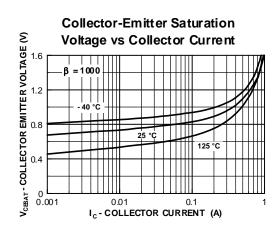
Electrical Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units		
OFF CHARAC	OFF CHARACTERISTICS						
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu A, I_B = 0$	-30		V		
I _{CBO}	Collector-Cutoff Current	$V_{CB} = -30V, I_{E} = 0$		-100	nA		
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = -10V, I_{C} = 0$		-100	nA		
ON CHARACTERISTICS*							
h _{FE}	DC Current Gain	I _C = -10mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V	10,000 20,000				
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = -100 \text{mA}, I_B = -0.1 \text{mA}$		-1.5	V		
V _{BE(on)}	Base-Emitter On Voltage	$I_C = -100 \text{mA}, V_{CE} = -5.0 \text{V}$		-2.0	V		
SMALL SIGNAL CHARACTERISTICS							
f _T	Current Gain - Bandwidth Product	$I_C = -10 \text{mA}, V_{CE} = -5.0 \text{V},$ f = 100 MHz	125		MHz		

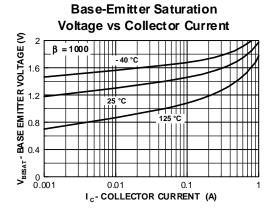
^{*} Pulse Test: Pulse Width $\leq 300 \mu s, \, Duty \, Cycle \leq 2.0\%$

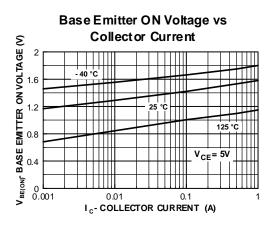
Typical Performance Characteristics



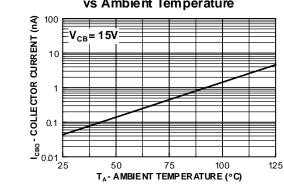


Typical Performance Characteristics (continued)

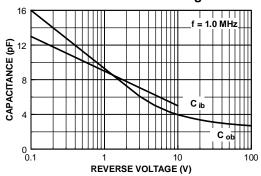




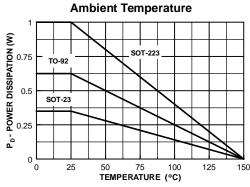




Input and Output Capacitance vs Reverse Bias Voltage



Power Dissipation vs







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Definition of Terms			
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